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STTH3R04

Ultrafast recovery diode

Features

- Negligible switching losses
- Low forward and reverse recovery times
- High junction temperature

Description

The STTH3R04 series uses ST's new 400 V planar Pt doping technology. The STTH3R04 is specially suited for switching mode base drive and transistor circuits.

Packaged in axial and surface mount packages, this device is intended for use in low voltage, high frequency inverters, free wheeling and polarity protection.

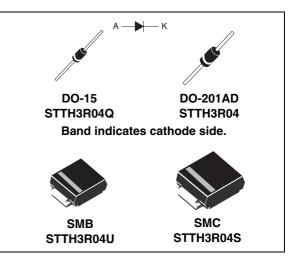


Table 1.Device summary

I _{F(AV)}	3 A
V _{RRM}	400 V
T _{j (max)}	175 °C
V _{F (typ)}	0.9 V
t _{rr (typ)}	18 ns

1 Characteristics

Table 2. Absolute ratings (limiting values at 25 °C, unless otherwise specified)

Symbol	Parame		Value	Unit	
V _{RRM}	Repetitive peak reverse voltage	400	V		
		DO-15	T _{lead} = 70 °C		
1		DO-201AD	T _{lead} = 80 °C	3.0	А
IF(AV)	Average forward current, 6 = 0.5	SMB	T _{lead} = 70 °C	3.0	A
		SMC	T _{lead} = 100 °C		
I _{FSM}	Surge non repetitive forward current	t _p = 10 ms Sir	nusoidal	60	А
T _{stg}	Storage temperature range	-65 to +175	°C		
Тj	Maximum operating junction tempera	ature ⁽¹⁾		175	°C

1. On infinite heatsink with 10 mm lead length

Table 3.Thermal parameters

Symbol	Parameter			Value	Unit
D	Junction to lead	Lead length = 10 mm	DO-15	25	
R _{th(j-l)}	Junction to lead	on infinite heatsink	DO-201AD	22	°C/W
Р	Junction to lead	·	SMB	25	0/00
R _{th(j-l)}	Junction to lead		SMC	17	

Table 4. Static electrical characteristics

Symbol	Parameter	Test conditions		Min	Тур	Max	Unit
I _B ⁽¹⁾	Reverse leakage current	T _j = 25 °C	V - V			5	
'R`	neverse leakage current	T _j = 125 °C	$V_{R} = V_{RRM}$		5	50	μΑ
		T _j = 25 °C				1.5	
V _F ⁽²⁾	Forward voltage drop	T _j = 100 °C	I _F = 3.0 A		1.0	1.25	V
		T _j = 150 °C			0.9	1.15	

1. Pulse test: t_p = 5 ms, δ < 2 %

2. Pulse test: $t_p = 380 \ \mu s, \ \delta < 2 \ \%$

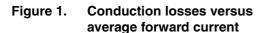
To evaluate the conduction losses use the following equation:

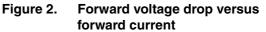
 $P = 0.9 \text{ x } I_{F(AV)} + 0.083 \text{ x } {I_F}^2_{(RMS)}$

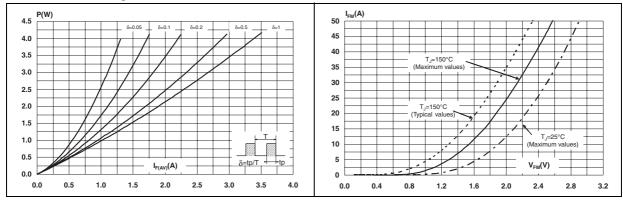


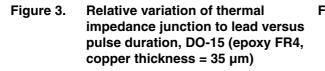
Symbol	Parameter	Test conditions	Min	Тур	Max	Unit
+	$I_{F} = 1 \text{ A}, \text{ d}I_{F}/\text{d}t = -50 \text{ A}/\mu\text{s},$ $V_{R} = 30 \text{ V}, T_{j} = 25 ^{\circ}\text{C}$				35	ns
t _{rr}	Reverse recovery time	$\label{eq:lastic_states} \begin{array}{l} I_F = 1 \ A, \ dI_F/dt = -100 \ A/\mus, \\ V_R = 30 \ V, \ T_j = 25 \ ^\circC \end{array}$		18	25	115
I _{RM}	Reverse recovery current	I _F = 3.0 A, dI _F /dt = -200 A/µs, V _R = 320 V, T _j = 125 °C		4	5.5	А
t _{fr}	Forward recovery time	$I_{F} = 3.0 \text{ A} \qquad dI_{F}/dt = 100 \text{ A}/\mu\text{s}$ $V_{FR} = 1.1 \text{ x} \text{ V}_{Fmax}, \text{ T}_{j} = 25 \text{ °C}$			75	ns
V _{FP}	Forward recovery voltage	I _F = 3.0 A dI _F /dt = 100 A/μs		2.5		V

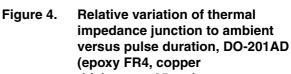
Table 5. Dynamic characteristics (Tj = 25 °C unless otherwise stated)











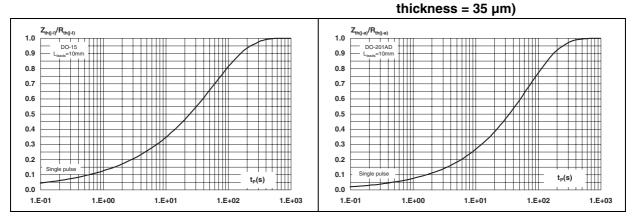
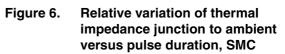
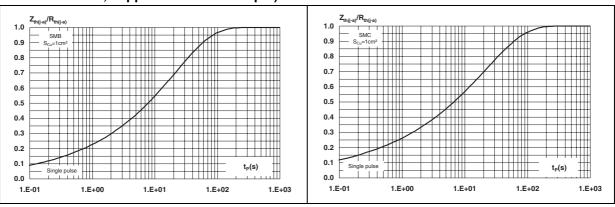


Figure 5. Relative variation of thermal impedance junction to ambient versus pulse duration, SMB (epoxy FR4, copper thickness = 35 μm)





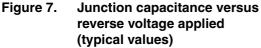


Figure 8. Reverse recovery charges versus dl_F/dt (typical values)

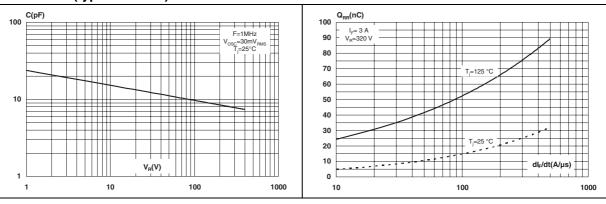


Figure 9. Reverse recovery time versus dl_F/dt (typical values)

Figure 10. Peak reverse recovery current versus dl_F/dt (typical values)

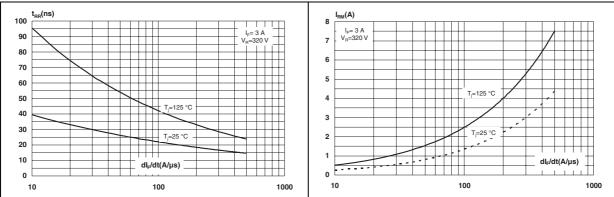


Figure 11. Relative variations of dynamic parameters versus junction temperature

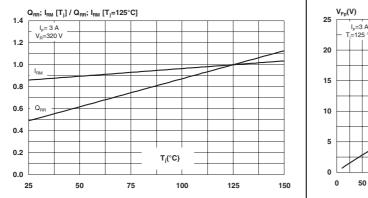


Figure 13. Forward recovery time versus dl_F/dt (typical values)

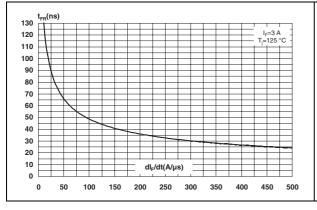
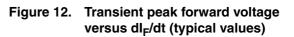


Figure 15. Thermal resistance junction to ambient versus copper surface under each lead, DO-201AD (epoxy FR4, copper thickness = 35 µm)



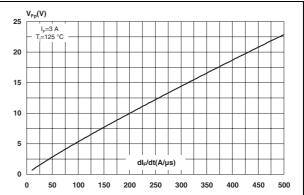


Figure 14. Thermal resistance versus lead length, DO-15

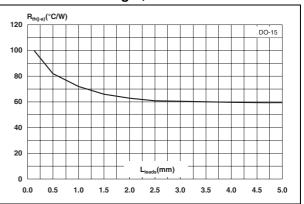
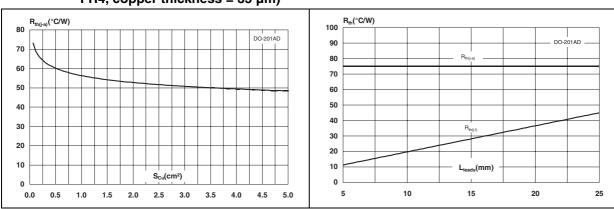


Figure 16. Thermal resistance versus lead length, DO-201AD



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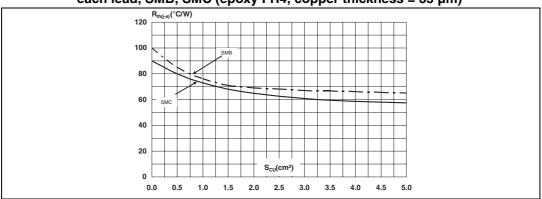


Figure 17. Thermal resistance junction to ambient versus copper surface under each lead, SMB, SMC (epoxy FR4, copper thickness = 35μ m)

2 Package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)

In order to meet environmental requirements, ST offers these devices in ECOPACK[®] packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at *www.st.com*.

			Dimer	sions	
	Ref.	Millim	neters	Incl	nes
		Min.	Max.	Min.	Max.
B A B Note 1 + E E + + Note 1	Α		9.50		0.374
	В	25.40		1.000	
// [ØD // ← Note 2	С		5.30		0.209
<u>oc</u>	D		1.30		0.051
	E		1.25		0.049
	Notes	controlled 2 - The mi straight be	over zone inimum len	gth which i right angle	nust stay

Table 6. DO201AD dimensions

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Table 7.	DO-15 dimensio	JII5					
					Dimer	nsions	
¢ C	A	C ,	Ref.	Millim	neters	Inc	hes
				Min.	Max.	Min.	Max.
		1	А	6.05	6.75	0.238	0.266
D		I	В	2.95	3.53	0.116	0.139
	В		С	26	31	1.024	1.220
			D	0.71	0.88	0.028	0.035

Table 7.DO-15 dimensions



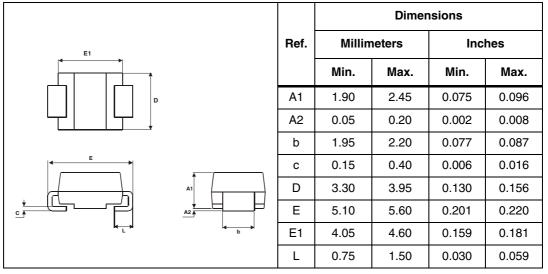
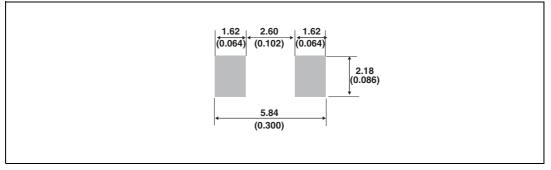


Figure 18. Footprint, dimensions in mm (inches)

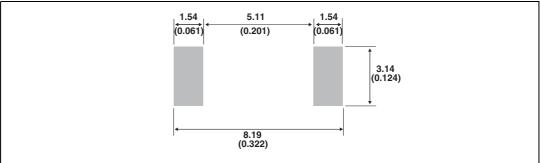


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				Dimer	nsions	
		Ref.	Millim	neters	Inc	hes
€1			Min.	Max.	Min.	Max.
		A1	1.90	2.45	0.075	0.096
D		A2	0.05	0.20	0.002	0.008
		b	2.90	3.20	0.114	0.126
E		с	0.15	0.40	0.006	0.016
	\uparrow	D	5.55	6.25	0.218	0.246
		Е	7.75	8.15	0.305	0.321
		E1	6.60	7.15	0.260	0.281
		E2	4.40	4.70	0.173	0.185
		L	0.75	1.50	0.030	0.059

Table 9.SMC dimensions





3 Ordering information

Table 10.	Ordering	information
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Order code	Marking	Package	Weight	Base qty	Delivery mode
STTH3R04	STTH3R04	DO-201AD	1.16 g	600	Ammopack
STTH3R04RL	STTH3R04	DO-201AD	1.16g	1900	Tape and reel
STTH3R04Q	STTH3R04Q	DO-15	0.4 g	1000	Ammopack
STTH3R04QRL	STTH3R04Q	DO-15	0.4 g	6000	Tape and reel
STTH3R04S	R4S	SMC	0.243 g	2500	Tape and reel
STTH3R04U	3R4U	SMB	0.12 g	2500	Tape and reel

4 Revision history

Table 11. Document revision history

Date	Revision	Description of changes
30-May-2008	1	First issue



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